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Correlation between structural parameters and the magnetocaloric effect in epitaxial La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ thin film

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Abstract
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Keywords
between, effect, epitaxial, structural, film, correlation, thin, la0, laalo3, 2mno3, 8ca0, parameters, magnetocaloric

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An epitaxial La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ (LCMO/LAO) thin film was fabricated using the pulsed laser deposition technique to evaluate the correlation between the crystal structure and the magnetocaloric effect. In our study, the LCMO film was 200 nm in thickness and appeared to have a strong out-of-plane texture. We found that each column in the LCMO thin film layer is a domain which has a different ordering direction. These microscopic feature results in anisotropic properties of magnetization, entropy, and relative cooling power. The film exhibited a paramagnetic-to-ferromagnetic second order phase transition at 249 K. The lack of any hysteresis loss also confirmed that the material is intrinsically reversible. In addition, the large magnetization of the thin film results in an entropy change larger than those of all other perovskite type materials. Consequently, the relative cooling power is significantly enhanced. © 2013 American Institute of Physics. [http://dx.doi.org/10.1063/1.4790876]

I. INTRODUCTION

Compressorless refrigeration represents one of future energy saving innovations. Magnetic refrigeration, based on large thermal changes driven by a magnetic field, is an important development in the quest for energy-efficient and environmentally friendly technologies. Materials exhibiting the giant magnetocaloric effect (MCE) have demonstrated potential for advancing magnetic refrigeration, a considerable socio-economic benefited alternative to conventional refrigeration. Since the discovery of the giant MCE phenomenon, giant MCE has been found in a large variety of magnetic materials, including Gd, Gd$_3$(Si$_{1-x}$Ge$_x$)$_4$, MnAs$_{1-x}$Sb$_x$, MnFe$_3$(P$_{1-x}$As$_x$)$_4$, La(Fe$_{1-x}$Si$_x$)$_3$, and RM$_2$ (where R = rare earth, M = Al, Co, Ni). Further efforts to discover new materials, especially materials without rare-earth elements and exhibiting large MCE in response to low applied field, are of significant importance. Among them, perovskite-type manganese oxide materials having large MCE are believed to be potential candidates for magnetic refrigeration applications.

In particular, the lanthanum manganite (LaMnO$_3$) family shows the perovskite structure. Here, the transition metal atoms of pure lanthanum manganite are predominantly in the state Mn$^{4+}$. Upon substitution of a divalent ion (such as Ca$^{2+}$, Ba$^{2+}$, or Sr$^{2+}$) on the rare earth site, an equal number of Mn$^{4+}$ ions are created at the expense of Mn$^{3+}$. The resulting compound can then be written, for instance, in the case of Ca substitution, as (La$_{1-x}$Ca$_x$)$_{3+}$ (Mn$_{1-x}$)$_{3+}$ (Mn$_x$)$_{4+}$. The intricate magnetic behavior of this compound is determined by the nature of the magnetic interactions between the mixed valence Mn ions. Very recently, the thin film structure has been receiving increased attention because it is easy to integrate into electronic structures for applications.

Interest in lanthanum manganite has been rekindled in the last few years due to the observation of large magnetoresistance in films deposited by pulsed laser deposition. Thin films of La-Ca-Mn-O, La-Ba-Mn-O, La-(Ca,Pb)-Mn-O, La-Ce-Mn-O, and La-Sr-Mn-O exhibit magnetoresistance in the range of 5%-150%, which is comparable to that obtained in giant magnetoresistance (GMR) metal multilayers. Jin et al. and McCormack et al. reported a “colossal” magnetoresistance of more than 100 000% for epitaxial La-Ca-Mn-O films on LaAlO$_3$. The origin of these enormous magnetoresistance values is unknown, although they evidently are related to the magnetic state of the system. The very large magnetization obtainable in this system near room temperature has also led us to study the magnetocaloric behavior of doped LaMnO$_3$ films.

It should be mentioned that most of today’s research activity in this field is limited to bulk and single crystal perovskite-type manganese oxide materials, but studies on thin film for MCE are very limited. Recently, scientists have started doing research on the MCE properties of thin films, but only a few reports are currently available, although in principle, such films will be easier to integrate into electronic structures for applications.

However, with the currently available magnetic materials, this high efficiency is only realized in high magnetic fields. Nanostructuring is a promising route to perturb properties and may lead to novel and advantageous magnetocaloric properties using existing materials. As La$_{0.8}$Ca$_{0.2}$MnO$_3$ (LCMO) is traditionally the standard by which all perovskite-type manganese oxide materials are measured, we have begun investigating the impact of nanostructuring using La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film with a simple monoclinic structure.

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In this work, we fabricated an epitaxial La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ (LCMO/LAO) thin film by pulsed laser deposition (PLD). It is speculated that this structure would help to improve the performance of the materials by maximizing the entropy change, suppressing hysteresis losses, adjusting the operation temperature, and reducing the required magnetic field. In addition, thin films show phase diagrams that are much richer than those for the corresponding bulk materials. This is because thin films emerge with two additional external variables, i.e., the film thickness and the epitaxial stress caused by lattice mismatch between the film and the substrate. The epitaxial strain in thin films can change the Jahn-Teller (JT) distortions of Mn$^{3+}$ octahedra, leading to strong electron-phonon coupling, which may produce substantial effects that act on various aspects of the film, including the growth mode, imperfections, and the associated structural and physical properties. Therefore, it is necessary to evaluate the correlation between the MCE and the microstructure in detail.

While a wide range of materials have been studied thus far, magnetocaloric materials have been largely unexplored on the nanoscale. Because nanostructuring is a well known approach used to perturb and tune structure-property relationships, associated techniques are being applied to study the MCE in nanoparticles and thin films. In this sense, the study of MCE in LCMO thin film is of great interest for testing the viability of LCMO as the nucleus of refrigeration systems.

II. EXPERIMENTAL DETAILS

The epitaxial LCMO film (~200 nm) was grown on a (100) LaAlO$_3$ substrate by PLD at Institute for Superconducting and Electronic Materials (ISEM), University of Wollongong, Australia. A short pulse excimer laser ($\lambda = 248$ nm) was focused onto a stoichiometric LCMO target with an estimated energy density of ~3.2 J cm$^{-2}$ and a repetition rate of 5 Hz. The oxygen pressure in the deposition chamber was maintained at 800 Torr, while the temperature of the substrate was at 700°C during the preparation process. The film thickness was controlled by the deposition time, which was at a rate of 100 nm/min. Following the deposition, the film was cooled to room temperature over 2 h in an oxygen atmosphere without any further thermal treatment.

For transmission electron microscopy (TEM), a thin sample was prepared by ion milling in a JEOL JEM-9320FIB. The sample was attached to a molybdenum TEM grid. This film was observed in a transmission electron microscope (JEOL JEM-2100F) equipped with energy dispersive spectroscopy (EDS). The epitaxial and lattice parameters of the film were examined and calculated from the data obtained using X-ray diffraction. Magnetization measurements were performed using a physical properties measurement system (PPMS) with a 14 T magnetometer in the temperature range from 5 to 200 K and magnetic fields up to 5 T. To measure the magnetic entropy change, $\Delta S_M$, from M(H) plot, we used a sweep rate of 50 Oe/s.

III. RESULT AND DISCUSSION

Figure 1(a) shows the X-ray diffraction pattern of a La$_{0.8}$Ca$_{0.2}$MnO$_3$ film deposited on LaAlO$_3$ substrate. It appears to have a strong out-of-plane texture, reflecting (00l). It is well known that thin film quality can be basically evaluated by the full-width at half maximum (FWHM) of important peaks. The corresponding FWHMs of the (002) and (004) peaks were 0.1340° and 0.2620°, respectively, for La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film on the LaAlO$_3$ substrate ($a = 3.79$ Å), indicating the excellent c-axis orientation of all the films. In addition, the crystal structure of our sample is exactly matched with the monoclinic structure ($a = 7.75$ Å, $b = 7.745$ Å, $c = 7.75$ Å) from X-ray refinement analysis. A cross-sectional view is also shown in Figure 1(b). We observe that the interface between the substrate and the film is relatively uniform and sharp. The thickness of the La$_{0.8}$Ca$_{0.2}$MnO$_3$ layer was estimated to be 200 nm. To further clarify, there still needs to be deeper insight from the viewpoint of microstructure.

Figure 2(a) shows a TEM bright field image of a La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ thin film. Electron diffraction patterns were acquired from the La$_{0.8}$Ca$_{0.2}$MnO$_3$, the LaAlO$_3$, and the interface area, and the results are displayed in Figures 2(b)–2(d), respectively. Comparing the image in Figure 2(a) and the electron diffraction pattern in Figure 2(b), it is clear that the La$_{0.8}$Ca$_{0.2}$MnO$_3$ layer grew in the [001] direction. Here, an orientation relationship between La$_{0.8}$Ca$_{0.2}$MnO$_3$ and LaAlO$_3$ exists and is given by...
The lattice parameters of La$_{0.8}$Ca$_{0.2}$MnO$_3$ are almost double those of the LaAlO$_3$ substrate, as mentioned above. However, lattice misfit between the two phases exists, and this is responsible for the elongated diffraction spots in Figure 2(d). The actual intensity profiles of the white and red dashed lines in (d) are displayed in (e).

$$\frac{D_{\text{film}}}{D_{\text{substrate}}} = \frac{1}{R_{\text{film}}} - \frac{1}{R_{\text{substrate}}} \times 100 = \left(\frac{1}{R_{\text{substrate}}} \times \frac{1}{R_{\text{film}}} \times 100 - \frac{1}{R_{\text{substrate}}} \times R_{\text{film}} \times 100\right) \times 100,$$

where $D$ is the interplanar distance. The calculated value is about 1.9%. This large lattice misfit is responsible for the misfit dislocation at the La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ interface. The existence of misfit dislocations at the La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ interface was reported by Daoudi et al.

In the TEM bright field image, we can find these contrasts when we compare the La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ interface image in Figure 2(a) with that of Figure 1(b); irregular contrast at the interface in Figure 2(a) is attributable to the strain field around the interface. Interestingly, the dark contrasts show up in the LaAlO$_3$ substrate, as marked with red arrows.

The magnified columnar structure of the La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film is shown in Figure 3. The size of each column was estimated to be about 30 nm. The annular dark field scanning TEM (ADF-STEM) image in Figure 3(b) clearly reveals the existence of dislocations around La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ interface where there are areas of dark contrast in Figure 2(a). Interestingly, it is clear that all the dislocations are located in the LaAlO$_3$ substrate region. This suggests that the LaAlO$_3$...
substrate accommodates lattice misfit strain between La$_{0.8}$Ca$_{0.2}$MnO$_3$ and LaAlO$_3$.

Figure 4(a) shows a bright field (BF) image of a La$_{0.8}$Ca$_{0.2}$MnO$_3$/LaAlO$_3$ thin film. There are many columns in the La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film layer. We investigated a high resolution image of the interface, which is denoted by the rectangle in Figure 4(a), between two neighboring columns (Figure 4(b)). The fast Fourier transform (FFT) patterns of selected areas 1 and 2 are displayed in Figures 4(c) and 4(d), respectively. These two patterns clearly show that these two areas are not different grains but different domains. The domains are ordered perpendicular each other. Therefore, each column in the La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film layer is a domain which has a different ordering direction. The existence of domain structures in La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film has been previously reported. To confirm the domain structure, we analyzed two adjacent columns by the nano-beam diffraction method. The beam size was 1.6 nm, so that the size was sufficient to acquire information from only one column. Figures 4(e) and 4(f) show the results. These results are in agreement with those of the high resolution analysis in Figures 4(c) and 4(d).

Figure 5(a) shows the temperature dependence of the magnetization (M-T) for different field directions. The Curie temperature ($T_C$) was estimated to be 249 K. In the literature, the $T_C$ values of bulk specimens and single crystals with the same composition were around 230 and 176 K, respectively. It is noteworthy that there is a drastic change in the magnetization around $T_C$ in the $ab$ plane (H//ab). However, the magnetization along the $c$-axis (H//c) seems to be insensitive to increasing temperature. This is mainly due to the columnar structure of $c$-axis alignment observed in the TEM. So it seems that magnetization in the ab plane (H//ab) is the easy and $c$-axis (H//c) is the hard direction of magnetization for the thin film. Hysteresis loops (M-H) of the thin film are also shown in Figure 5(b). Interestingly, there is no magnetic hysteresis, which indicates that the MCE is fully reversible and confirms the second-order character of the ferromagnetic-paramagnetic (FM-PM) transition. We also collected initial magnetization isotherms in the vicinity of $T_C$. From the Banerjee criterion, phase transition of our thin film appears typically second order. We also confirmed that $T_C$ is approximately 249 K from Arrott plots (not shown). This is quite comparable with the results shown in Figure 5(a).

The magnetic entropy changes in the La$_{0.8}$Ca$_{0.2}$MnO$_3$ thin film for different magnetic field directions are shown in Figure 6. $|\Delta S_M|$ shows a peak with its maximum around 247 K near $T_C$. The maximum values of $|\Delta S_M|$ were estimated.
to be 35.90, 27.50, and 24.97 mJcm⁻³K⁻¹ under a field change of 1 T for the different field directions, H//ab, H//45°, and H//c, respectively. Corresponding values were 112.9, 102.6, and 101 mJcm⁻³K⁻¹ under a 5 T magnetic field change. What is interesting is that a large low-field magnetic entropy change along the ab-plane is observed. The maximum values of |ΔSM| are about 35.9 and 61.18 mJcm⁻³K⁻¹ for a magnetic field change of 1 T and 2 T, respectively. These values of |ΔSM| are on the same order of magnitude as that of Gd⁴⁶ and are even higher than in many perovskite manganites.⁴³,⁴⁴ These low-field large magnetic entropy changes in the thin film are mainly due to the rapid change in the magnetization near the transition temperature in the easy magnetizing plane. In the La₀.₈Ca₀.₂MnO₃ thin film, there are two exchange interactions, i.e., the intralayer exchange interaction, Jab, and the interlayer exchange interaction, Jc. Because J_ab is much stronger than J_c, the magnetic moments tend to lie in the ab-plane. In the vicinity of T_C, a small magnetic field along the ab-plane can easily promote the paramagnetic to ferromagnetic transition, which causes a rapid change in the magnetization. As a result, a low magnetic field can induce considerable magnetic entropy change.

Relative cooling power (RCP) of the thin film is shown in Figure 7. It shows large RCP values (i.e., ~1000 mJcm⁻³ for the ab plane and ~780 mJcm⁻³ for the c-direction), which are higher than those observed in several other perovskite manganites and rare earth alloys.⁸,¹⁰,⁴³ One of the interesting features of Figure 6 is that the |ΔSM| peaks in all directions are significantly broadened over a wider temperature region than in the corresponding polycrystalline LCMO, due to higher nanostructural disorder.³²,³³ In fact, the observed larger temperature FWHM, T_FWHM, for the peak at low field may indicate that nanostructuring is a potential route for developing magnetic refrigerants with large useful temperature ranges.

IV. CONCLUSIONS

In this study, MCE of epitaxial La₀.₈Ca₀.₂MnO₃/LaAlO₃ thin film was investigated. In contrast to the bulk form of La₀.₈Ca₀.₂MnO₃ and other perovskites, the magnetic anisotropy, the texture of the material, and film morphology have strong influence on the MCE properties. The La₀.₈Ca₀.₂MnO₃ thin film shows an anisotropic entropy change of 35.9 and 24.97 mJcm⁻³K⁻¹ in 1 T magnetic field change for the ab-plane and the c-direction, respectively. This larger entropy change value and the enhanced entropy change FWHM is ideal for electronic cooling device. The higher entropy change value and higher RCP with no noticeable hysteresis loss may also make it more convenient for use as a magnetic refrigerator. This indicates that thin film processing might provide an alternative pathway in searching for efficient magnetic refrigerators for microscale systems.

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